

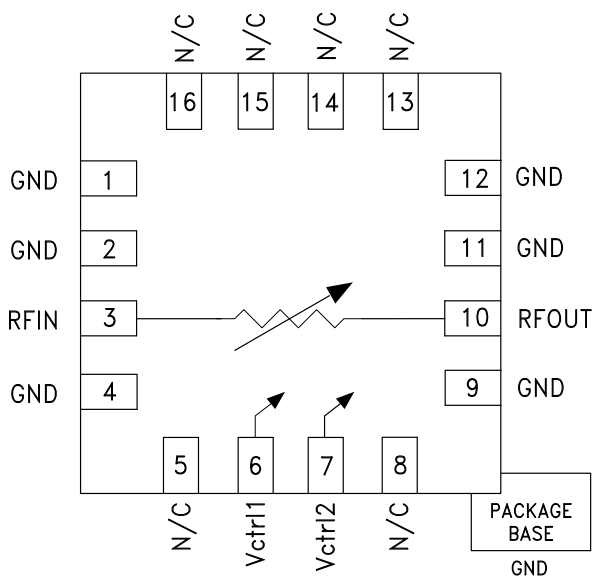
GaAs MMIC VOLTAGE-VARIABLE ATTENUATOR, 5 - 26.5 GHz

Typical Applications

The HMC712ALP3CE is ideal for:

- Point-to-Point Radio
- VSAT Radio
- Test Instrumentation
- Microwave Sensors
- Military, ECM & Radar

Functional Diagram



Features

- Wide Bandwidth: 5 - 26.5 GHz
- Excellent Linearity: +28 dBm Input P1dB
- Wide Attenuation Range: 28 dB
- Absorptive Topology
- Singe or Dual Control Operation
- 16 Lead 3x3mm SMT Package: 9mm²

General Description

The HMC712ALP3CE is an absorptive Voltage Variable Attenuator (VVA) which operates from 5 - 26.5 GHz and is ideal in designs where an analog DC control signal must be used to control RF signal levels over a 28 dB amplitude range. It features two shunt-type attenuators which are controlled by two analog voltages, Vctrl1 and Vctrl2. Optimum linearity performance of the attenuator is achieved by first varying Vctrl1 of the 1st attenuation stage from -5V to 0V with Vctrl2 fixed at -5V. The control voltage of the 2nd attenuation stage, Vctrl2, should then be varied from -5V to 0V, with Vctrl1 fixed at 0V. The HMC712ALP3CE is housed in a RoHS compliant 3x3 mm QFN leadless package

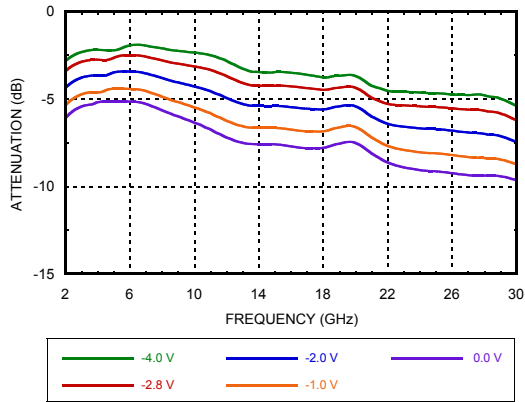
Furthermore, if the Vctrl1 and Vctrl2 pins are connected together it is possible to achieve the full analog attenuation range with only a small degradation in input IP3 performance. Applications include AGC circuits and temperature compensation of multiple gain stages in microwave point-to-point and VSAT radios.

Electrical Specifications, $T_A = +25^\circ\text{C}$, 50 Ohm system

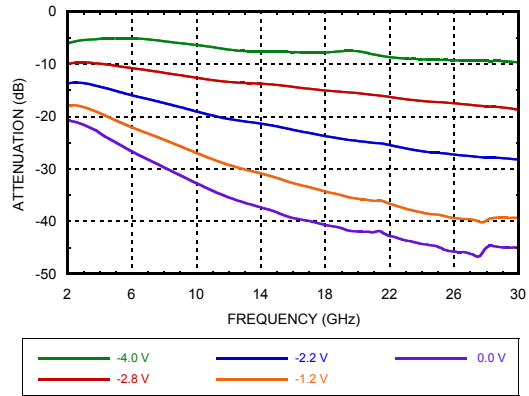
| Parameter | Min. | Typ. | Max. | Units |
|--|---------------|------|------|-------|
| Insertion Loss | 5 - 10 GHz | 2.3 | 3.5 | dB |
| | 10 - 15 GHz | 3 | 4 | dB |
| | 15 - 26.5 GHz | 4.2 | 5.7 | dB |
| Attenuation Range | 5 - 10 GHz | 19 | 27 | dB |
| | 10 - 15 GHz | 21 | 32 | dB |
| | 15 - 26.5 GHz | 23 | 37 | dB |
| Input Return Loss | | 12 | | dB |
| Output Return Loss | | 10 | | dB |
| Input Power for 1 dB Compression (any attenuation) | | 28 | | dBm |
| Input Third Order Intercept (Two-tone Input Power = 10 dBm Each Tone) | | 32 | | dBm |

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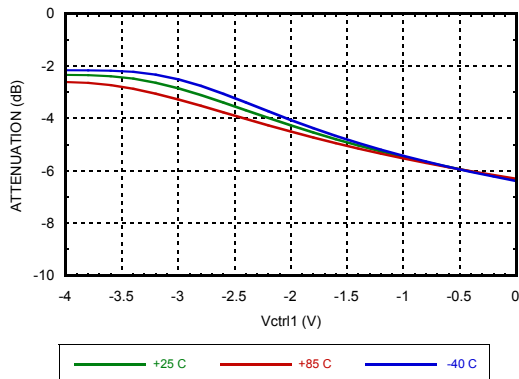
Attenuation vs. Frequency over Vctrl
Vctrl1 = Variable, Vctrl2 = -5V



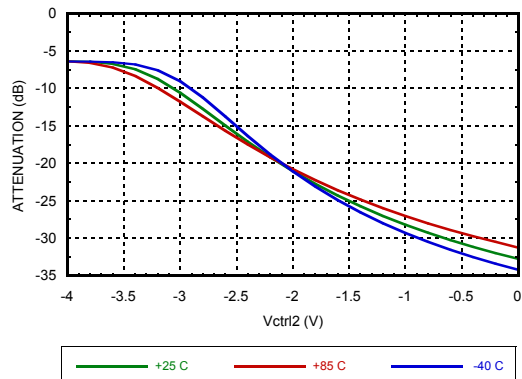
Attenuation vs. Frequency over Vctrl
Vctrl1 = 0V, Vctrl2 = Variable



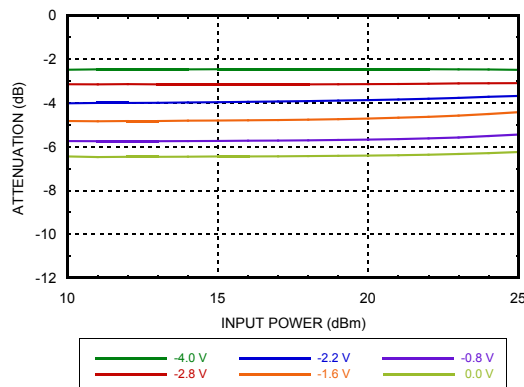
Attenuation vs. Vctrl1
Over Temperature @ 10 GHz, Vctrl2 = -5V



Attenuation vs. Vctrl2
Over Temperature @ 10 GHz, Vctrl1 = 0V

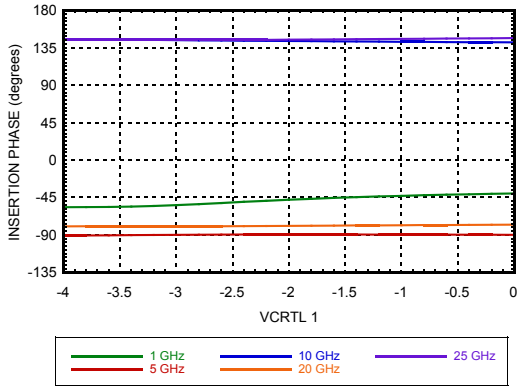


Attenuation vs. Pin @ 10 GHz
Vctrl1 = Variable, Vctrl2 = -5V

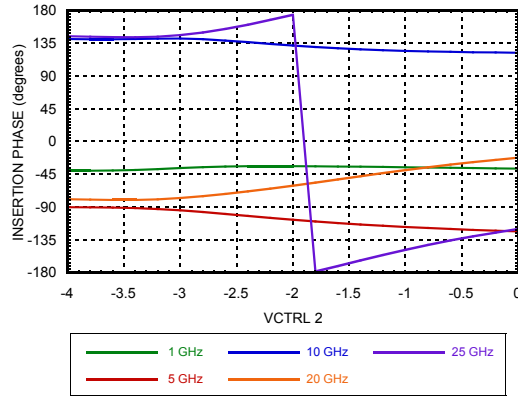


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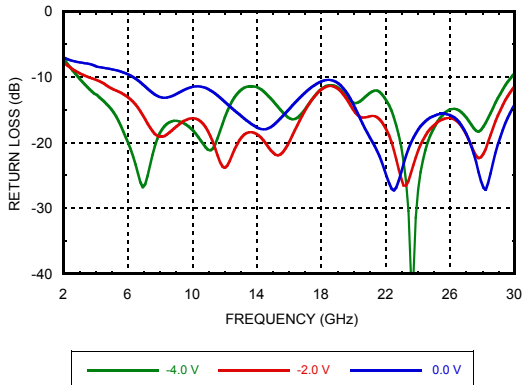
Insertion Phase vs. Vctrl1, Vctrl2 = -5V



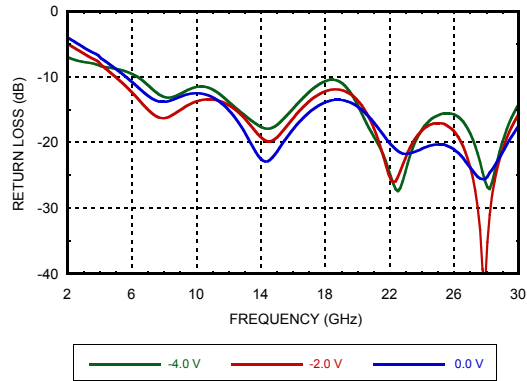
Insertion Phase vs. Vctrl2, Vctrl1 = 0V



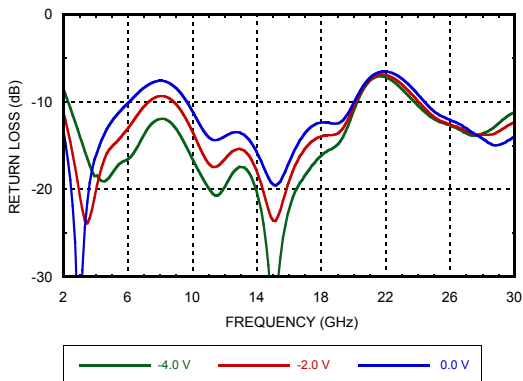
**Input Return Loss
Vctrl1 = Variable, Vctrl2 = -5V**



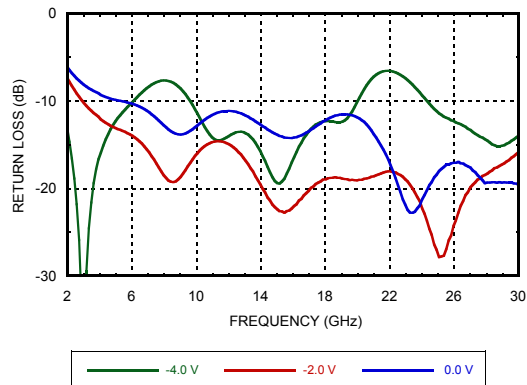
**Input Return Loss
Vctrl1 = 0V, Vctrl2 = Variable**



**Output Return Loss
Vctrl1 = Variable, Vctrl2 = -5V**

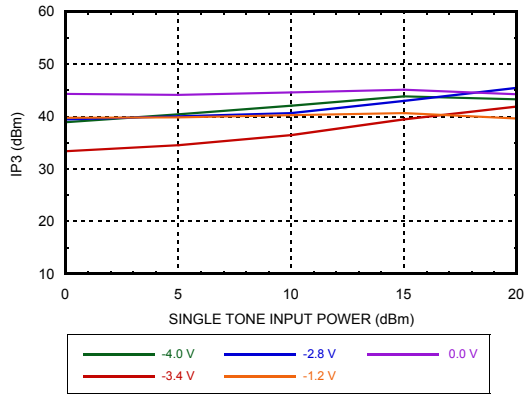


**Output Return Loss
Vctrl1 = 0V, Vctrl2 = Variable**

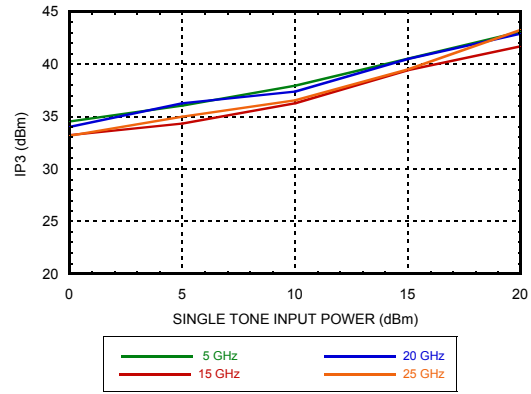


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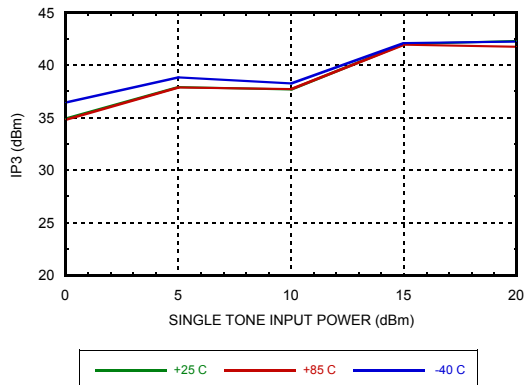
Input IP3 vs Input Power @ 10 GHz
Vctrl1 = Variable, Vctrl2 = -5V



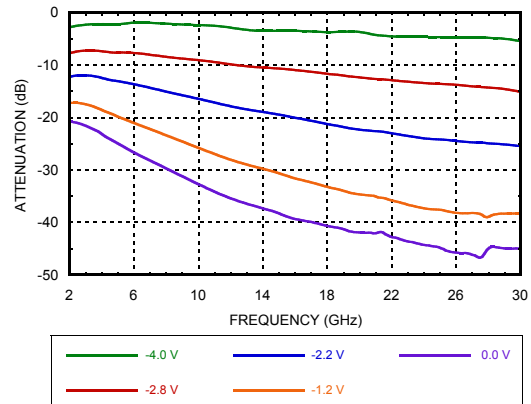
Input IP3 vs. Input Power Over Frequency
Vctrl1 = -2.0V, Vctrl2 = -5V (Worst Case IP3)



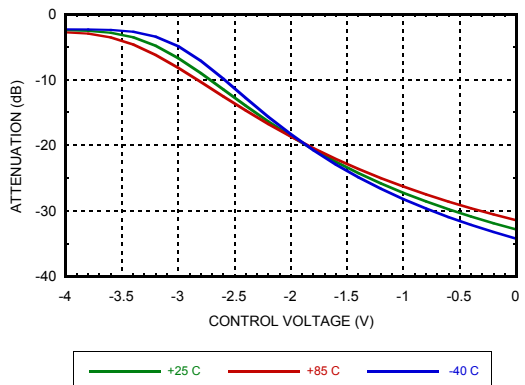
Input IP3 vs. Input Power Over Temperature
@ 10 GHz, Vctrl1 = -2.0V, Vctrl2 = -5V



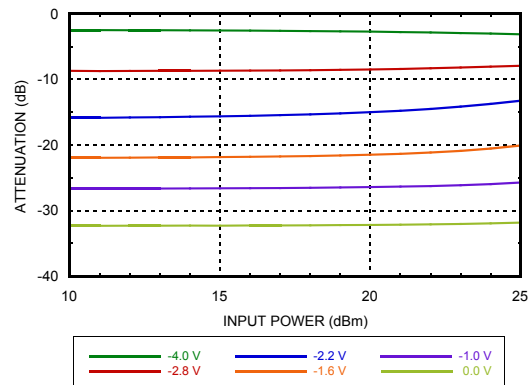
Attenuation vs. Frequency over Vctrl
Vctrl1 = Vctrl2



Attenuation vs. Vctrl over Temperature
@ 10 GHz, Vctrl1 = Vctrl2

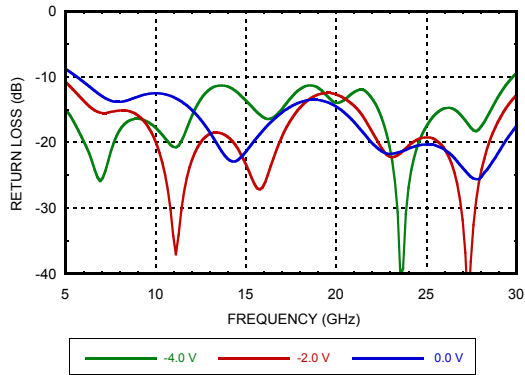


Attenuation vs. Input Power over Vctrl
Vctrl1 = Vctrl2

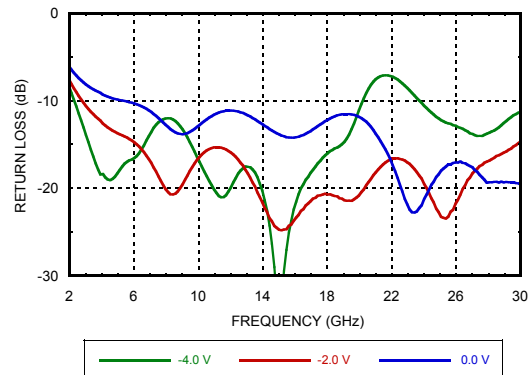


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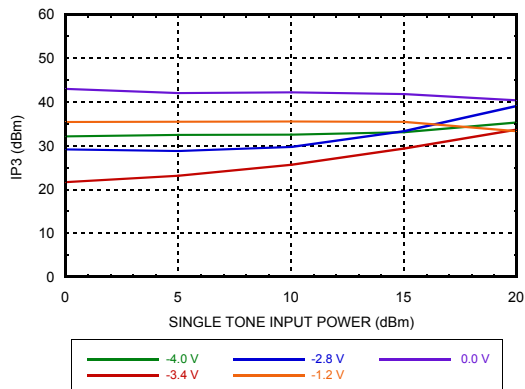
Input Return Loss, Vctrl1 = Vctrl2



Output Return Loss, Vctrl1 = Vctrl2



Input IP3 vs. Input Power Over Vctrl @ 10 GHz, Vctrl1 = Vctrl2



Absolute Maximum Ratings

| | |
|---|-----------------------|
| RF Input Power | +30 dBm |
| Control Voltage Range | +0.3 to -6V |
| Channel Temperature | 175 °C |
| Continuous Pdiss (T = 85 °C) | 1W |
| Thermal Resistance (Channel to ground paddle) | 66 °C/W |
| Storage Temperature | -65 to +150 °C |
| Operating Temperature | -40 to +85 °C |
| ESD Sensitivity (HBM) | Class 0 (Passed 150V) |

Control Voltages

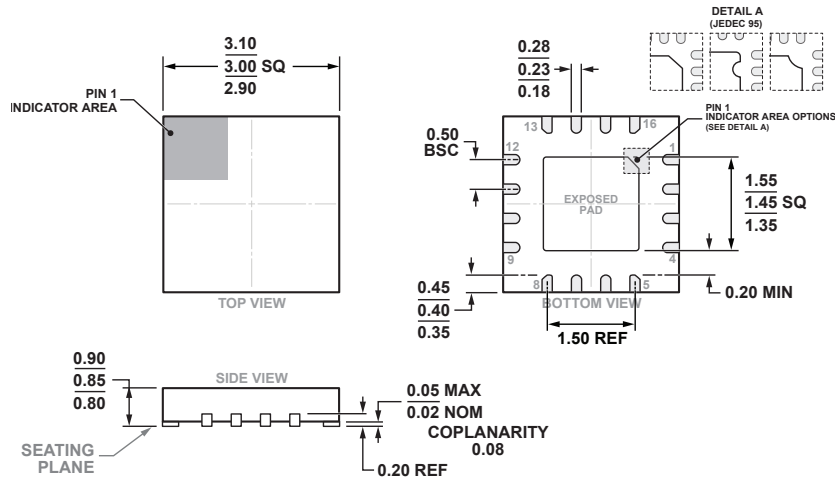
| | |
|--------|------------------|
| Vctrl1 | -5 to 0V @ 10 μA |
| Vctrl2 | -5 to 0V @ 10 μA |



ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

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Outline Drawing



COMPLIANT WITH JEDEC STANDARDS MO-220-VEED-4

16-Lead Lead Frame Chip Scale Package [LFCSP]
3 x 3 mm Body and 0.85 mm Package Height
(CP-16-52)

Dimensions shown in millimeters

Package Information

| Part Number | Package Body Material | Lead Finish | MSL Rating | Package Marking ^[1] |
|--------------|--|---------------|---------------------|--------------------------------|
| HMC712ALP3CE | RoHS-compliant Low Stress Injection Molded Plastic | 100% matte Sn | MSL3 ^[2] | H712A XXXX |

[1] 4-Digit lot number XXXX

[2] Max peak reflow temperature of 260 °C

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Pin Descriptions

| Pin Number | Function | Description | Interface Schematic |
|-------------------------------------|----------|--|---------------------|
| 1, 2, 4, 9, 11, 12 Ground Paddle | GND | Ground paddle must be connected to RF/DC ground. | |
| 3 | RFIN | This pin is DC coupled and matched to 50 Ohms. A blocking capacitor is required if RF line potential is not equal to 0V. | |
| 5, 8, 13 - 16 | N/C | These pins should be connected to PCB RF ground to maximize performance. | |
| 6 | Vctrl1 | Control Voltage 1 | |
| 7 | Vctrl2 | Control Voltage 2 | |
| 10 | RFOUT | This pin is DC coupled and matched to 50 Ohms. A blocking capacitor is required if RF line potential is not equal to 0V. | |

Application Circuit

